








	<h2>SI3424DV-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI3424DV-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 5A 6-TSOP</p> <p>Datenblätter:  SI3424DV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 23585 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3424DV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 5A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	23585 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	5A (Ta)
Rds On (Max) @ Id, Vgs	28 mOhm @ 6.7A, 10V
VGS (th) (Max) @ Id	800mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	18nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)















































SI3424DV-T1-GE3 ist neu im Original, Suche SI3424DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3424DV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3424DV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3424CDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 8A 6-TSOP</p>	 <p>SI3424DV VISHAY VISHAY SOT23-6</p>	 <p>SI3424DV-T1-E3 VISHAY SI3424DV-T1-E3 VISHAY</p>	 <p>SI3424DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 5A 6-TSOP</p>
 <p>SI3424DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 5A 6-TSOP</p>	 <p>SI3424DV-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 5A 6-TSOP</p>	 <p>SI3429EDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CHAN 20V TSOP6S</p>	 <p>SI3429EDV-T1-GE3 Vishay / Siliconix MOSFET P-CHAN 20V TSOP6S</p>

heiße Teile

Mehr

 SI3410DV-T1-E3	 SI3410DV-T1-E3	 SI3410DV-T1-GE3	 SI3410DV-T1-GE3	 SI3417DV-T1-GE3
 SI3417DV-T1-GE3	 SI3420DV-T1-GE3	 SI3421DV-T1-GE3	 SI3421DV-T1-GE3	 SI3422DV
 SI3422DV-T1	 SI3422DV-T1-GE3	 SI3424BDV	 SI3424BDV-T1-E3	 SI3424BDV-T1-E3
 SI3424BDV-T1-GE3	 SI3424BDV-T1-GE3	 SI3424CDV	 SI3424CDV-T1-E3	 SI3424CDV-T1-GE3
 SI3424CDV-T1-GE3	 SI3424DV-T1	 SI3424DV-T1-E3	 SI3424DV-T1-E3	 SI3424DV-T1-GE3
 SI3424DV-T1-E3	 SI3425DV	 SI3429EDV-T1-GE3	 SI3429EDV-T1-GE3	 SI3430DV-T1
 SI3430DV-T1-GE3	 SI3430DV-T1-GE3	 SI3433BDV-T1	 SI3433BDV-T1-E3	 SI3433BDV-T1-E3
 SI3433BDV-T1-GE3	 SI3433BDV-T1-GE3	 SI3433CDV-T1-E3	 SI3433CDV-T1-E3	 SI3433CDV-T1-GE3
 SI3433CDV-T1-GE3	 SI3433DN	 SI3433DV-T1	 SI3433DV-T1-E	 SI3433DV-T1-E3
 SI3433DV-T1-GE3	 SI3434DV-T1	 SI3434DV-T1-E3	 SI3434DV-T1-E3	 SI3434DV-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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